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Bib Data Sheet

CONFIRMATION NO. 6729

SERIAL NUMBER 09/239,948	FILING DATE 01/29/1999 RULE	CLASS 257	GROUP ART UNIT 2811	ATTORNEY DOCKET NO. 0756-1930
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APPLICANTS
SHUNPEI YAMAZAKI, TOKYO, JAPAN;
YASUHIKO TAKEMURA, KANAGAWA, JAPAN;

**** CONTINUING DATA *******
THIS APPLICATION IS A DIV OF 08/847,314 04/23/1997 PAT 5,965,915
AND A DIV OF 08/692,227 08/07/1996 PAT 5,789,292
WHICH IS A DIV OF 08/355,652 12/14/1994 PAT 5,569,615
WHICH IS A DIV OF 08/142,048 10/28/1993 PAT 5,541,138

**** FOREIGN APPLICATIONS *******
JAPAN 4-316138 10/30/1992
JAPAN 4-316138 10/30/1992

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
** 09/27/2001

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 8	TOTAL CLAIMS 16	INDEPENDENT CLAIMS 8
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature <i>[Signature]</i> Initials <i>[Initials]</i>				

ADDRESS
SIXBEY FRIEDMAN LEEDOM & FERGUSON
2010 CORPORATE RIDGE
SUITE 600
MCLEAN, VA 22102

TITLE *A Memory Device Having A Floating Gate*
LASER PROCESSING METHOD, METHOD FOR FORMING A FLASH MEMORY, INSULATED GATE SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME

FILING FEE RECEIVED 4498	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees (Filing)
		<input type="checkbox"/> 1.17 Fees (Processing Ext. of time)
		<input type="checkbox"/> 1.18 Fees (Issue)
		<input type="checkbox"/> Other _____
		<input type="checkbox"/> Credit

SERIAL NUMBER	FILING DATE	CLASS	GROUP ART UNIT	ATTORNEY DOCKET NO.
09/239,948	01/29/99	257	2811	0756-1930

APPLICANT

SHUNPEI YAMAZAKI, TOKYO, JAPAN; YASUHIKO TAKEMURA, KANAGAWA, JAPAN.

****CONTINUING DOMESTIC DATA*******

VERIFIED THIS APPLN IS A DIV OF 08/847,314 04/23/97 PAT 5,965,915
 AND A DIV OF 08/692,227 08/07/96 PAT 5,789,292
 AND A DIV OF 08/354,253 12/14/94 PAT 5,541,138
 AND A DIV OF 08/142,048 10/28/93 PAT 5,541,138

****371 (NAT'L STAGE) DATA*******

VERIFIED

****FOREIGN APPLICATIONS*******

VERIFIED JAPAN 4-316138 10/30/92

Foreign Priority claimed 35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	Met after Allowance	STATE OR COUNTRY JPX	SHEETS DRAWING 8	TOTAL CLAIMS 16	INDEPENDENT CLAIMS 8
Verified and Acknowledged			Examiner's Initials	Initials		

ADDRESS	SIXBEY FRIEDMAN LEEDOM & FERGUSON 2010 CORPORATE RIDGE SUITE 600 MCLEAN VA 22102
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TITLE	LASER PROCESSING METHOD, METHOD FOR FORMING A FLASH MEMORY, INSULATED GATE SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME A MEMORY DEVICE HAVING A FLOATING GATE
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FILING FEE RECEIVED \$1,150	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT NO. _____ for the following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
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